# NSN 5961-01-007-5844

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### Inclosure Material:

Metal

**Overall Length:** 

1.245 inches

# Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

0.687 inches

#### Thread Size:

0.250 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

350.0 collector to base voltage/static/emitter open and 325.0 collector to emitter voltage/static/base open

# **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

# Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

#### **Transfer Ratio:**

10.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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